Ordering number:EN3570

N-Channel Silicon MOSFET

2SK1432

Ultrahigh-Speed Switching Applications

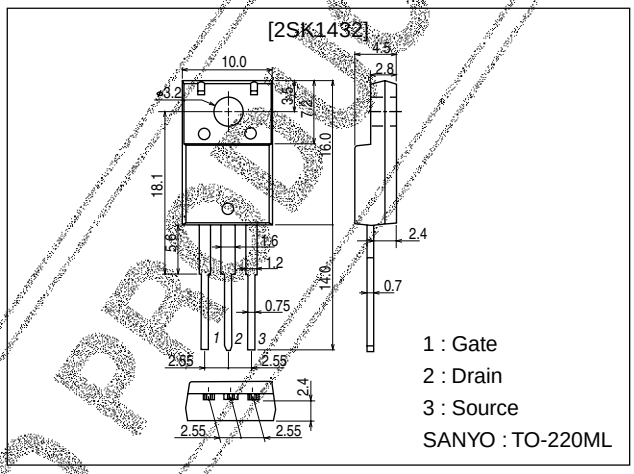
Features

- Low ON-state resistance.
- Ultrahigh-speed switching.
- Converters.
- Micaless package facilitating easy mounting.

Package Dimensions

unit:mm

2063A



Specifications

Absolute Maximum Ratings at Ta = 25˚C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		100	V
Gate-to-Source Voltage	V_{GSS}		±20	V
Drain Current (DC)	I_D		25	A
Drain Current (Pulse)	I_{DP}	PW≤10μs, duty cycle≤1%	100	A
Allowable Power Dissipation	P_D	Tc=25˚C	40	W
			2.0	W
Channel Temperature	Tch		150	˚C
Storage Temperature	Tstg		–55 to +150	˚C

Electrical Characteristics at Ta = 25˚C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	I_D=1mA, V_{GS}=0	100			V
Zero-Gate Voltage Drain Current	I_{DSS}	V_{DS}=100V, V_{GS}=0			100	μA
Gate-to-Source Leakage Current	I_{GSS}	V_{GS}=±20V, V_{DS}=0			±100	nA
Cutoff Voltage	$V_{GS(off)}$	V_{DS}=10V, I_D=1mA	1.5		2.5	V
Forward Transfer Admittance	|yfs|	V_{DS}=10V, I_D=20A	13	22		S
Static Drain-to-Source ON-State Resistance	$R_{DS(on)}$	I_D=20A, V_{GS}=10V		0.040	0.055	Ω

(Note) Be careful in handling the 2SK1432 because it has no protection diode between gate and source.

Continued on next page.

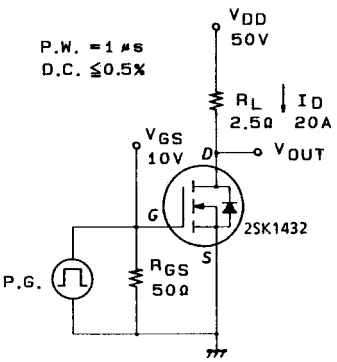
SANYO Electric Co.,Ltd. Semiconductor Company

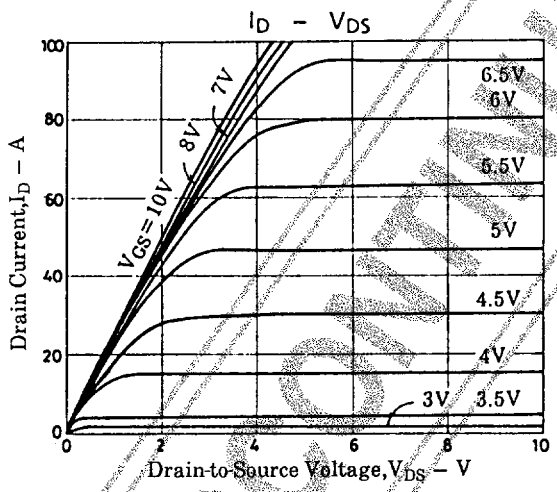
TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

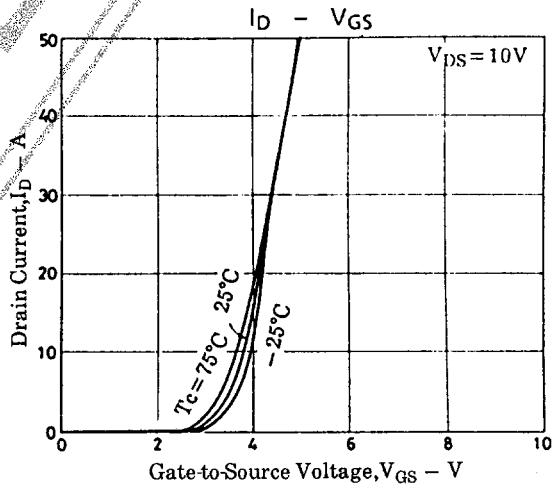
Continued from preceding page.

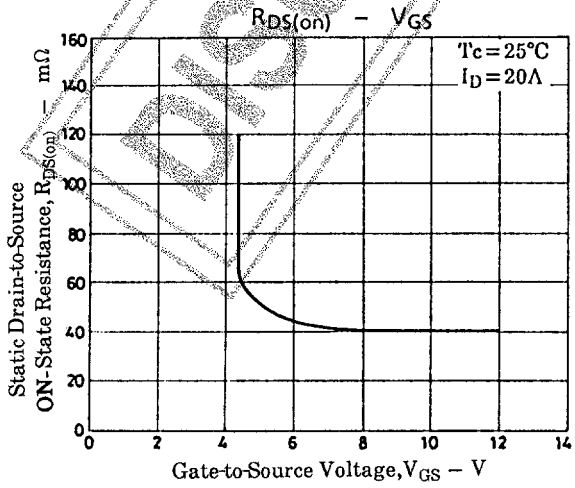
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	Ciss	V_{DS}=20V, f=1MHz		2400		pF
Output Capacitance	Coss	V_{DS}=20V, f=1MHz		700		pF
Reverse Transfer Capacitance	Crss	V_{DS}=20V, f=1MHz		200		pF
Turn-ON Delay Time	$t_{d(on)}$	I_D=20A, V_{GS}=10V, V_{DD}=50V, R_{GS}=50Ω		30		ns
Rise Time	t_r	I_D=20A, V_{GS}=10V, V_{DD}=50V, R_{GS}=50Ω		90		ns
Turn-OFF Delay Time	$t_{d(off)}$	I_D=20A, V_{GS}=10V, V_{DD}=50V, R_{GS}=50Ω		320		ns
Fall Time	t_f	I_D=20A, V_{GS}=10V, V_{DD}=50V, R_{GS}=50Ω		130		ns
Diode Forward Voltage	V_{SD}	I_S=25A, V_{GS}=0			1.8	V

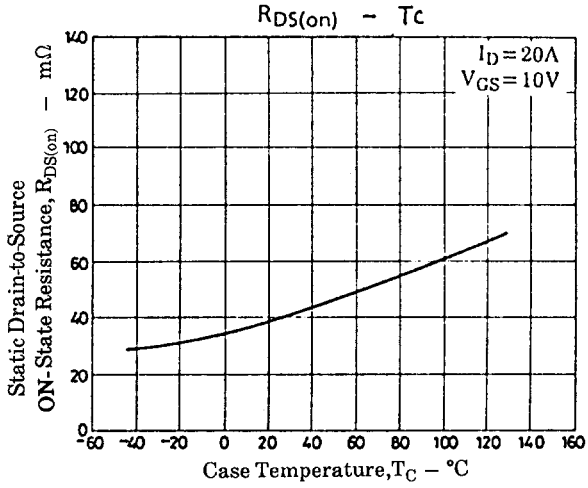
Switching Time Test Circuit

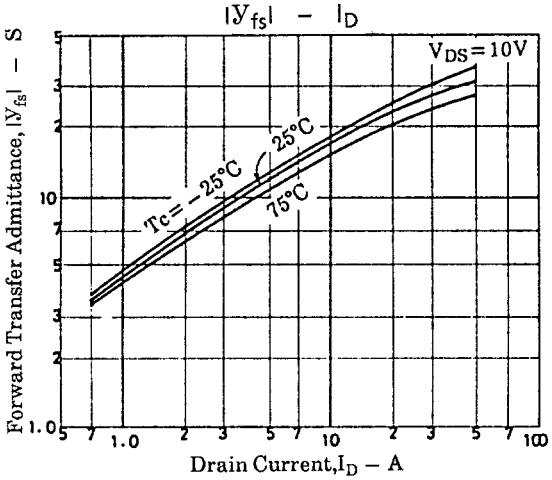


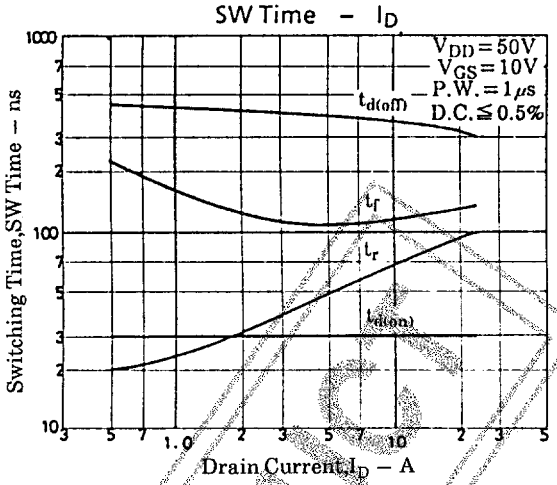


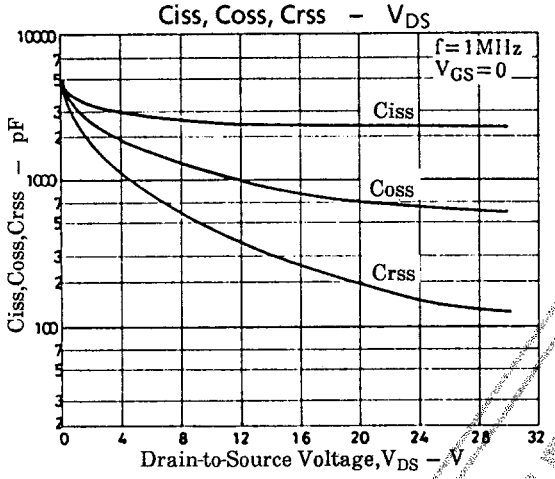


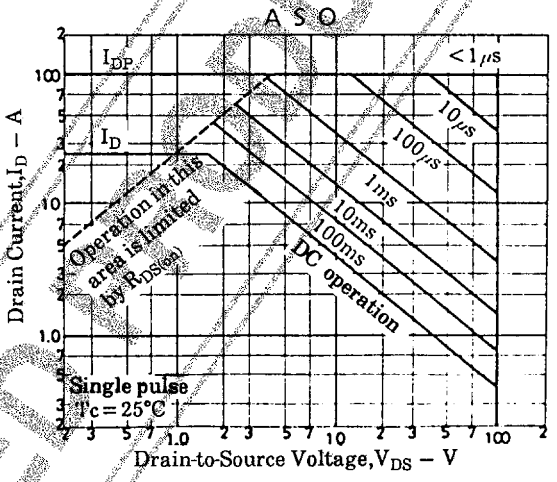


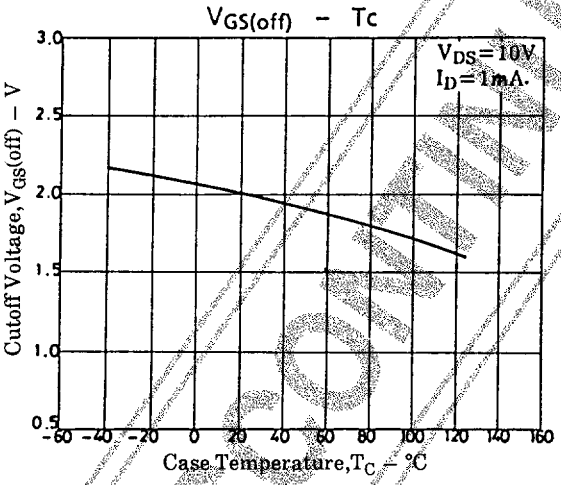


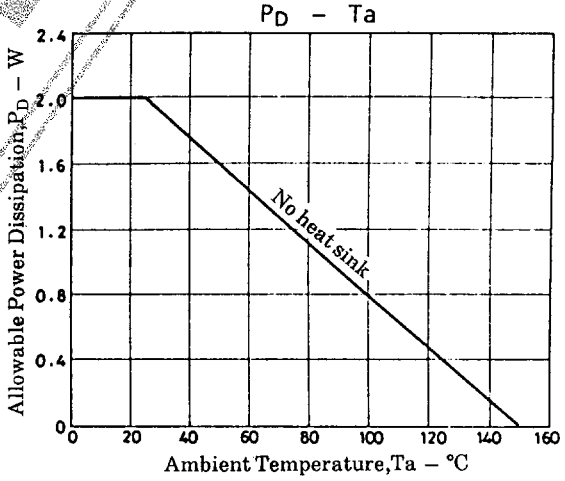


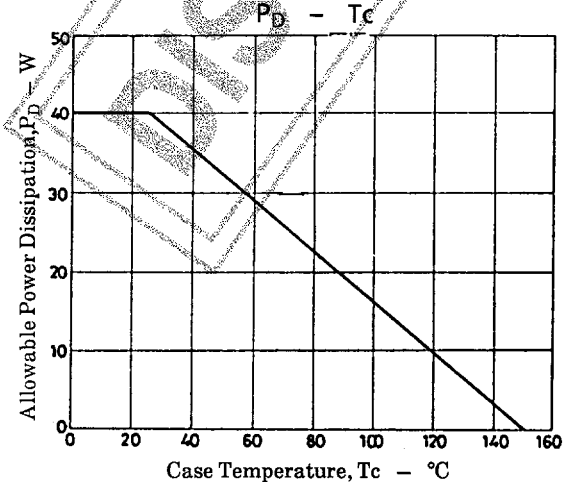












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